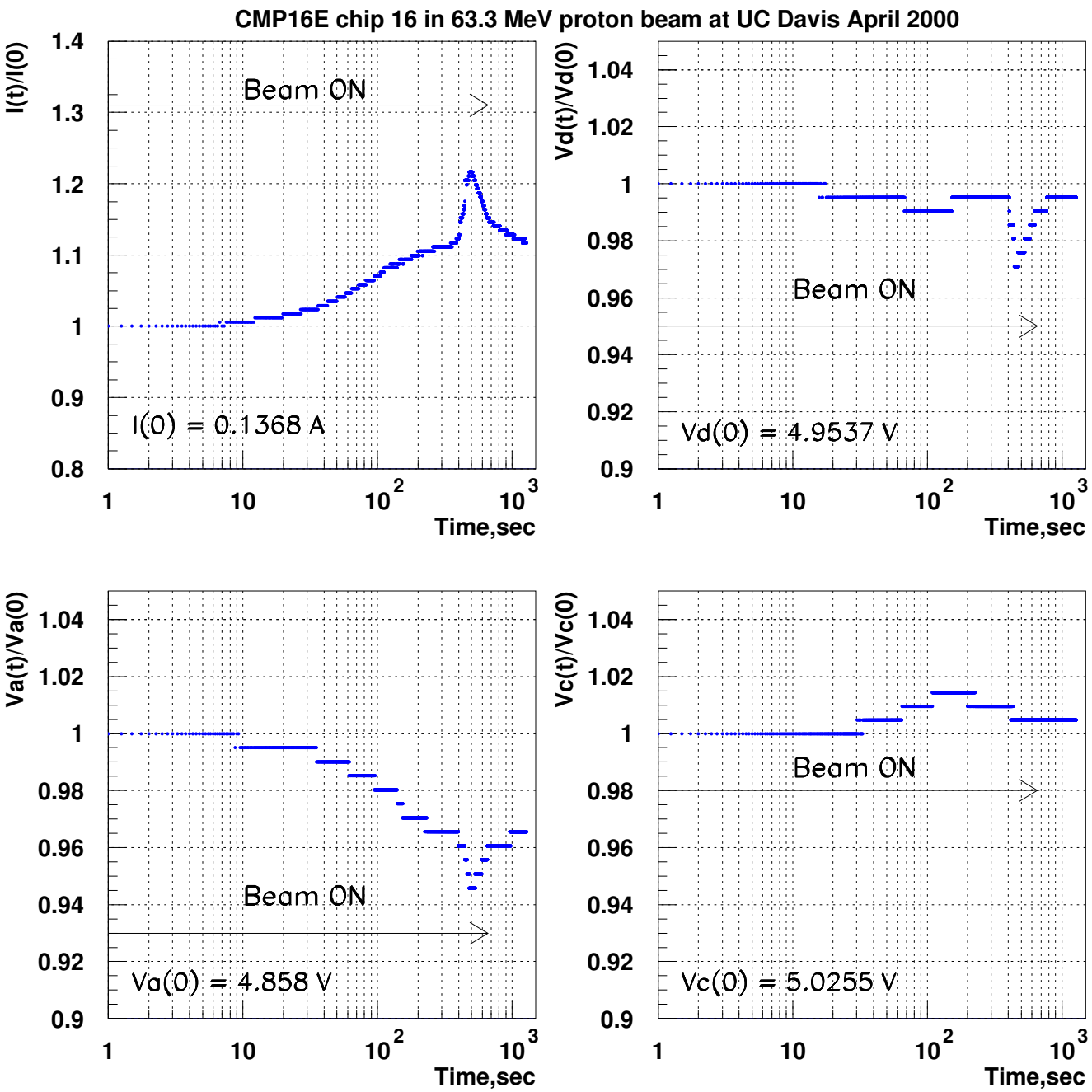
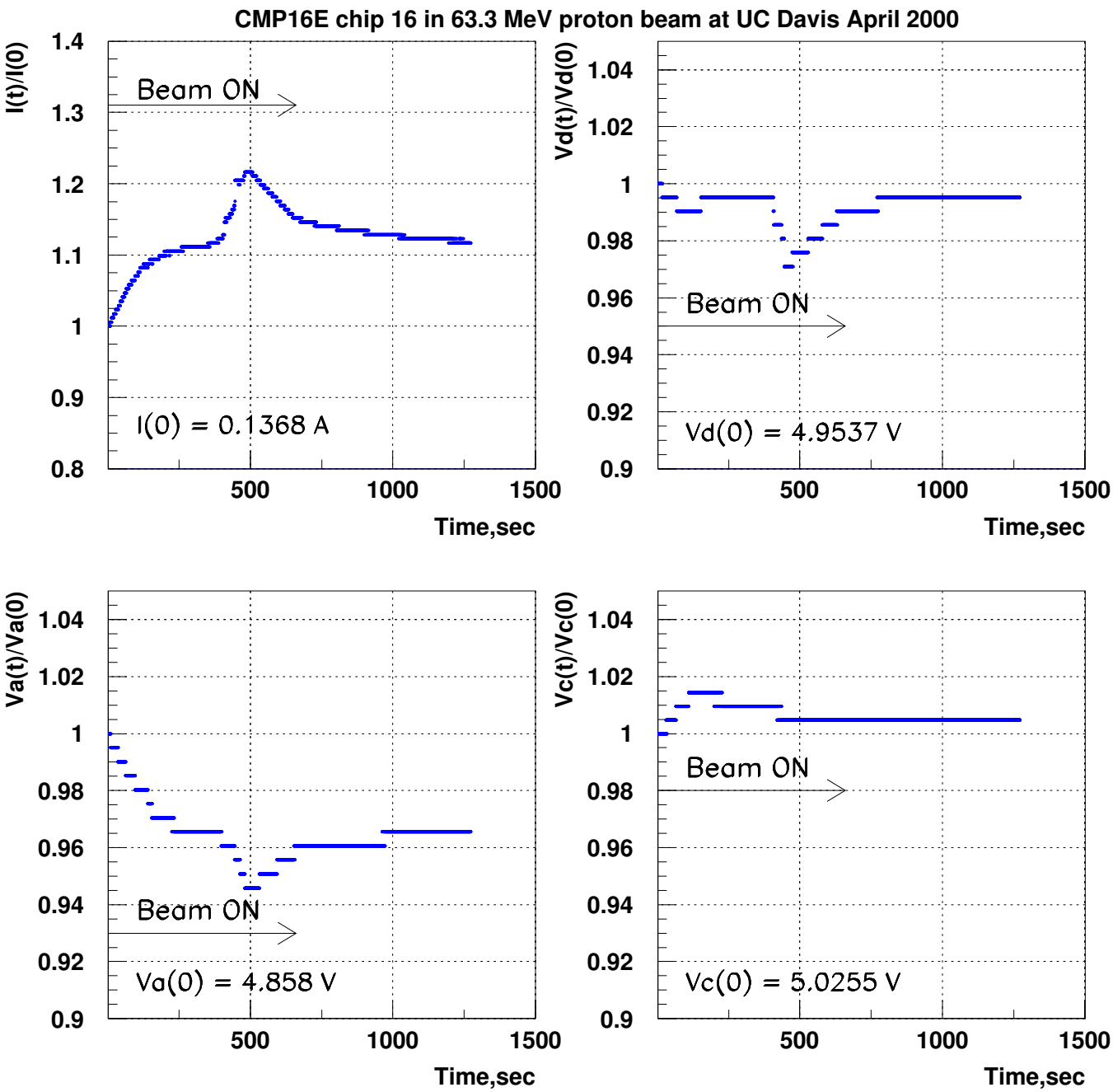
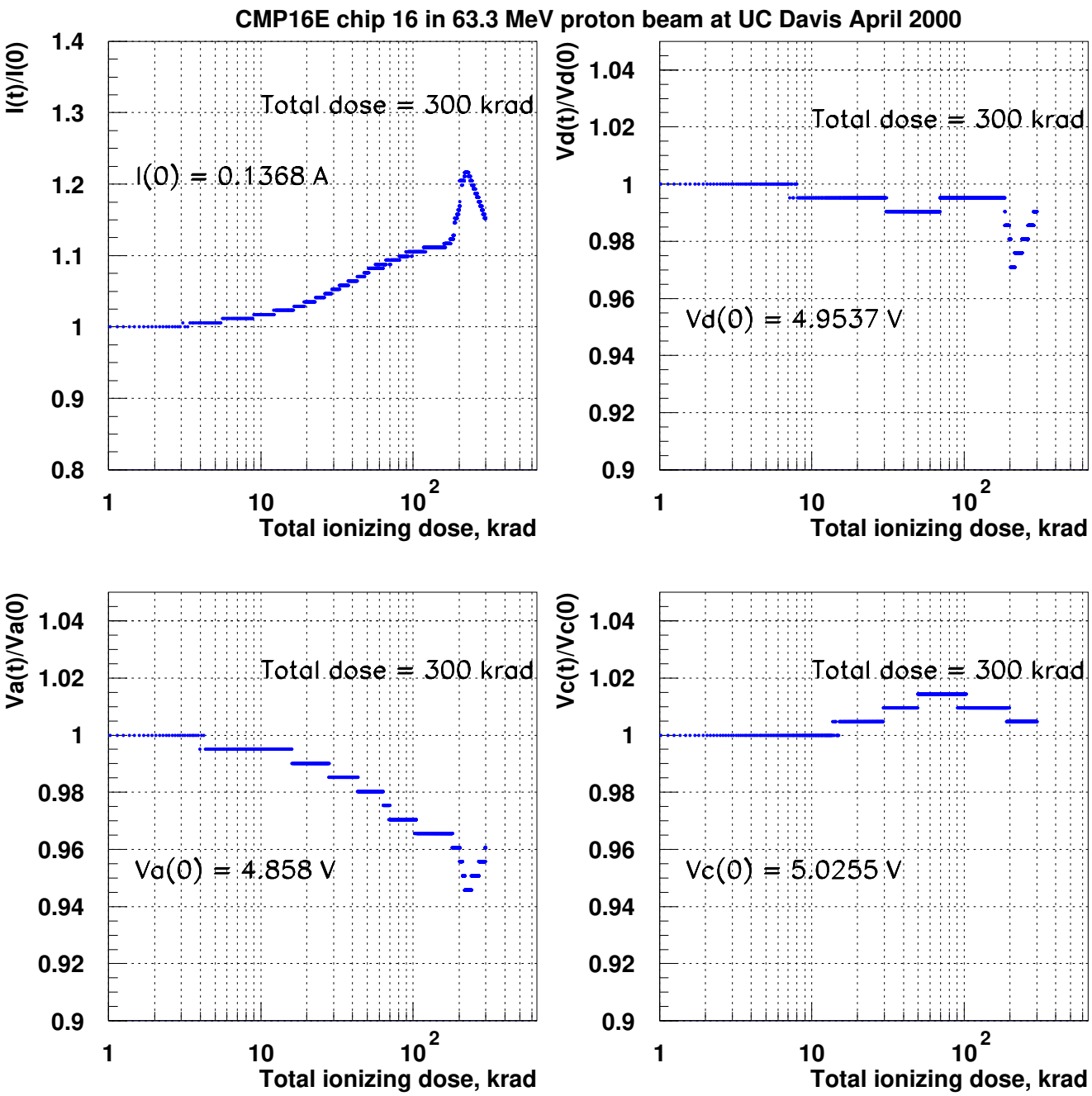
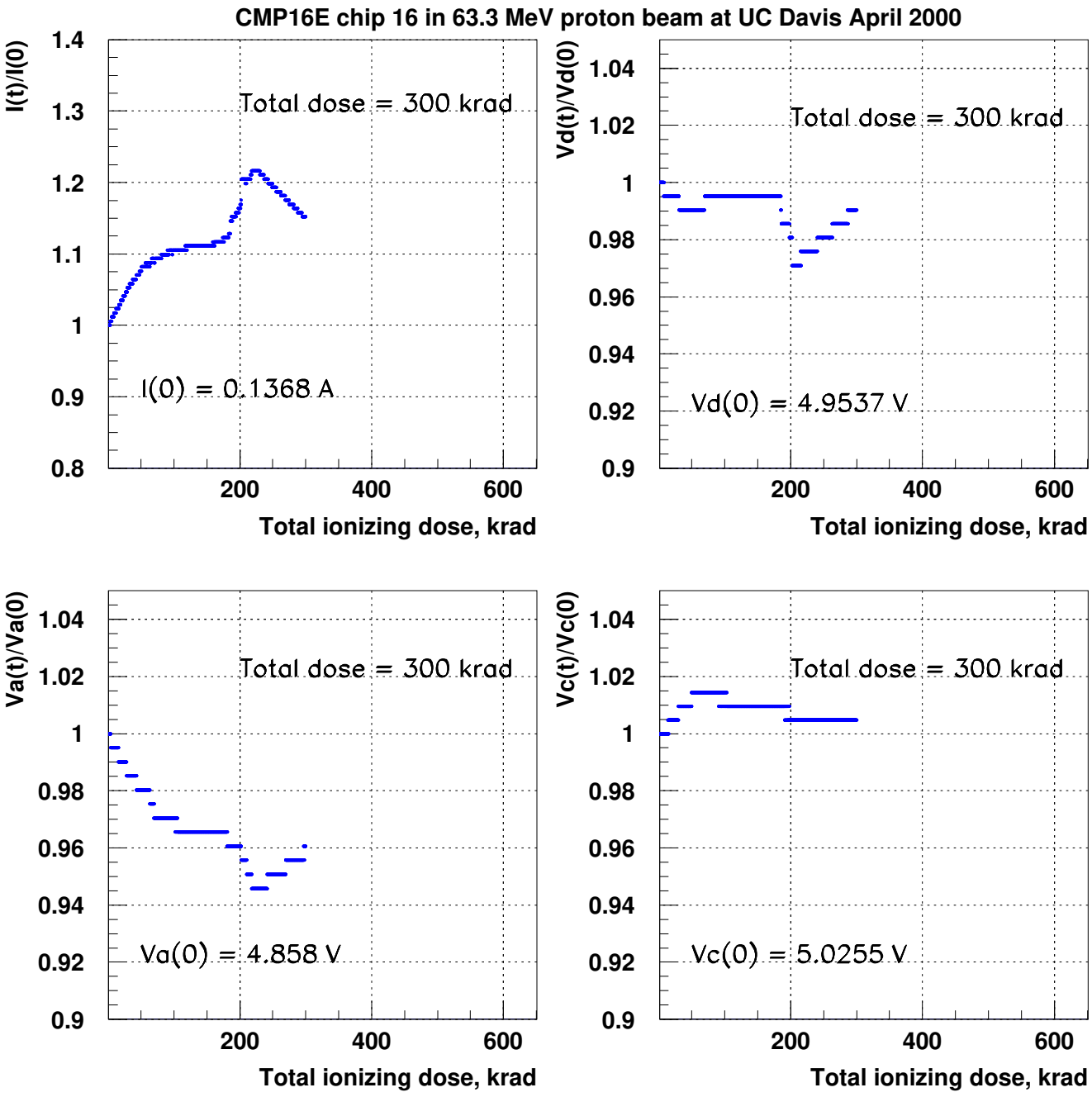

CMP16E chip 16 in 63.3 MeV proton beam at UC Davis April 2000
I(t)/I(0)
Beam ON
I(0) = 0.1368 A
Time,sec
Vd(t)/Vd(0)
Beam ON
Vd(0) = 4.9537 V
Time,sec
Va(t)/Va(0)
Beam ON
Va(0) = 4.858 V
Time,sec
Vc(t)/Vc(0)
Beam ON
Vc(0) = 5.0255 V
Time,sec


CMP16E chip 16 in 63.3 MeV proton beam at UC Davis April 2000
I(t)/I(0)
Beam ON
I(0) = 0.1368 A
Time,sec
Vd(t)/Vd(0)
Beam ON
Vd(0) = 4.9537 V
Time,sec
Va(t)/Va(0)
Beam ON
Va(0) = 4.858 V
Time,sec
Vc(t)/Vc(0)
Beam ON
Vc(0) = 5.0255 V
Time,sec


CMP16E chip 16 in 63.3 MeV proton beam at UC Davis April 2000
I(t)/I(0)
Total dose = 300 krad
I(0) = 0.1368 A
Total ionizing dose, krad
Vd(t)/Vd(0)
Total dose = 300 krad
Vd(0) = 4.9537 V
Total ionizing dose, krad
Va(t)/Va(0)
Total dose = 300 krad
Va(0) = 4.858 V
Total ionizing dose, krad
Vc(t)/Vc(0)
Total dose = 300 krad
Vc(0) = 5.0255 V
Total ionizing dose, krad


CMP16E chip 16 in 63.3 MeV proton beam at UC Davis April 2000
I(t)/I(0)
Total dose = 300 krad
I(0) = 0.1368 A
Total ionizing dose, krad
Vd(t)/Vd(0)
Total dose = 300 krad
Vd(0) = 4.9537 V
Total ionizing dose, krad
Va(t)/Va(0)
Total dose = 300 krad
Va(0) = 4.858 V
Total ionizing dose, krad
Vc(t)/Vc(0)
Total dose = 300 krad
Vc(0) = 5.0255 V
Total ionizing dose, krad